Electron-impact ionization cross-sections and rate coefficients for the Si-like ions Se²⁰⁺

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Synopsis Electron-impact ionization cross sections and rate coefficients for Si-like Se²⁰⁺ ion are calculated using semi-relativistic configuration-average distorted-wave (CADW) method for both the direct and indirect ionization contributions. The contribution from the excitation-autoionization channels originating from the single excitations of 2s and 2p subshells were calculated using a semi-relativistic level to level distorted-wave (LLDW) method.

Electron-impact ionization cross-sections and rate coefficients for the Si-like ions Se²⁰⁺, are presented. The direct ionization cross-sections of 2s, 2p, 3s and 3p ubshells are calculated us'ng CADWmethod[1]. In addition, excitation–autoionization contributions originating from the inner-shell excitations of the type

 $2s^22p^63s^23p^2 \rightarrow 2s^22p^53s^23p^2nl$ and

 $2s^22p^63s^23p^2 \rightarrow 2s^12p^63s^23p^2nl$ where n = 3 - 7 and l = 0 - 4 are calculated using both CADW and LLDW methods[1]. Branching ratios for the radiation damping of the autoionizing configurations and levels are included. Maxwellian averaged collision rates were calculated at a range of electron temperatures from cross-sections obtained in various approximations. The energies and bound orbitals needed to evaluate the cross-sections are calculated in the Hartree-Fock Relativistic (HFR) approximation [2], which includes the mass-velocity and Darwin corrections within modified Hartree-Fock differential equations. The continuum radial orbitals are obtained by solving a singlechannel Schrödinger equation, which also includes the mass-velocity and Darwin corrections, where the distorting potential is constructed from HFR bound orbitals.

It is interesting to note from Figure (a) that computationally simple configuration-average distorted wave cross-section calculations (σ_{WBR}^{CAEA}) are in good agreement with the computationally demanding level-resolved calculations (σ_{WBR}^{LLEA}) for the excitation-autoionization contributions for Se²⁰⁺ ion. WBR and NBR subscripts in Figure (a) and (b) represents the inclusion and exclusion of branching ratios from the calculations, respectively. The small disagreement between σ_{WBR}^{CAEA} and σ_{WBR}^{LLEA} are more prominent in the corresponding rate coefficients as shown in Figure (a) We hope the results in this presentation will encourage experimental measurements for such a complex case.



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References

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